



# VNL5090N3-E VNL5090S5-E

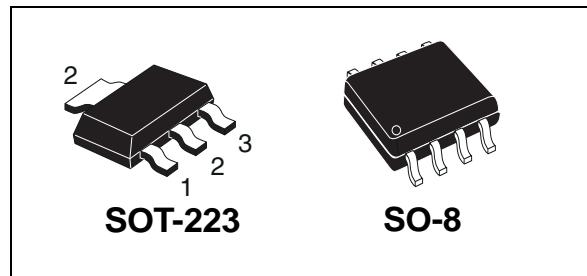
OMNIFET III  
fully protected low-side driver

Datasheet – production data

## Features

Type	V <sub>clamp</sub>	R <sub>DS(on)</sub>	I <sub>D</sub>
VNL5090N3-E	41 V	90 mΩ	13 A
VNL5090S5-E			

- Drain current: 13 A
- ESD protection
- Overvoltage clamp
- Thermal shutdown
- Current and power limitation
- Very low standby current
- Very low electromagnetic susceptibility
- Compliant with European directive 2002/95/EC
- Open drain status output (VNL5090S5-E only)
- Specially intended for 2 x R10W or 4 x R5W automotive signal lamps



## Description

The VNL5090N3-E and VNL5090S5-E are monolithic devices made using STMicroelectronics® VIPower® technology, intended for driving resistive or inductive loads with one side connected to the battery. Built-in thermal shutdown protects the chip from overtemperature and short-circuit.

Output current limitation protects the devices in an overload condition. In case of long duration overload, the device limits the dissipated power to a safe level up to thermal shutdown intervention. Thermal shutdown, with automatic restart, allows the devices to recover normal operation as soon as a fault condition disappears. Fast demagnetization of inductive loads is achieved at turn-off.

Table 1. Devices summary

Package	Order codes	
	Tube	Tape and reel
SOT-223	VNL5090N3-E	VNL5090N3TR-E
SO-8	VNL5090S5-E	VNL5090S5TR-E

## Contents

<b>1</b>	<b>Block diagrams and pins configurations</b>	<b>5</b>
<b>2</b>	<b>Electrical specifications</b>	<b>8</b>
2.1	Absolute maximum ratings	8
2.2	Thermal data	8
2.3	Electrical characteristics	9
<b>3</b>	<b>Application information</b>	<b>13</b>
3.1	MCU I/O protection	14
<b>4</b>	<b>Package and PC board thermal data</b>	<b>16</b>
4.1	SOT-223 thermal data	16
4.2	SO-8 thermal data	19
<b>5</b>	<b>Package and packing information</b>	<b>22</b>
5.1	ECOPACK®	22
5.2	SOT-223 mechanical data	22
5.3	SO-8 mechanical data	23
5.4	SOT-223 packing information	25
5.5	SO-8 packing information	26
<b>6</b>	<b>Revision history</b>	<b>27</b>

## List of tables

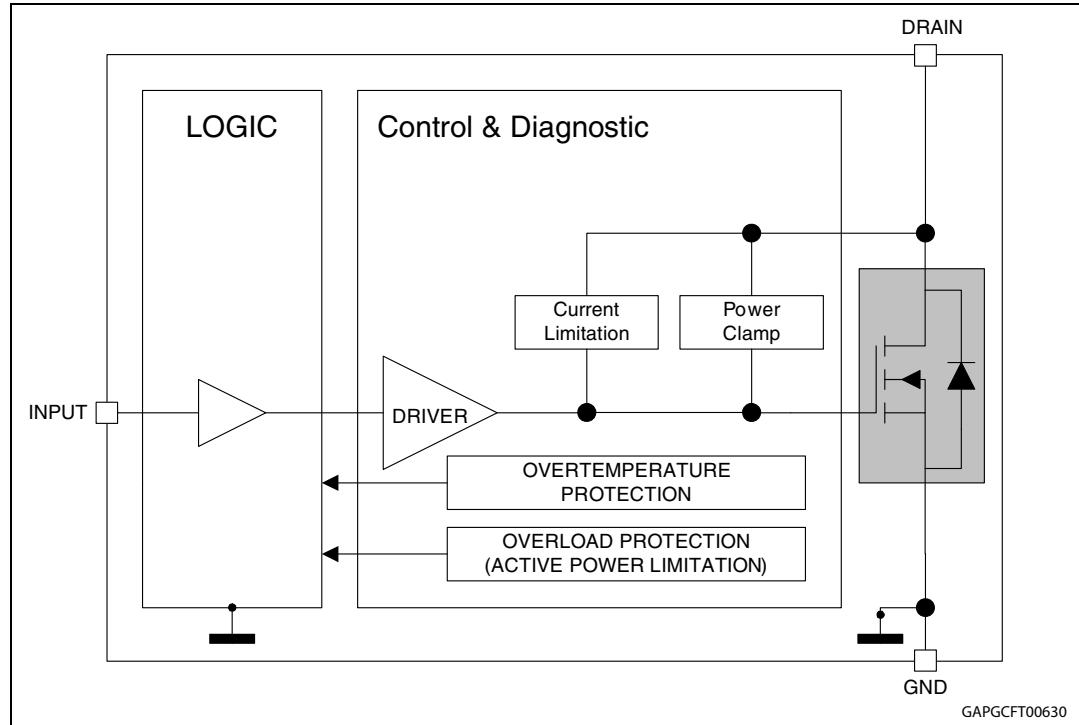
Table 1.	Devices summary .....	1
Table 2.	Pin function .....	6
Table 3.	Suggested connections for unused and N.C. pins .....	7
Table 4.	Absolute maximum ratings .....	8
Table 5.	Thermal data.....	8
Table 6.	PowerMOS section.....	9
Table 7.	Source drain diode .....	9
Table 8.	Input section. ....	9
Table 9.	Status pin .....	9
Table 10.	Logic input .....	10
Table 11.	Openload detection.....	10
Table 12.	Supply section .....	10
Table 13.	Switching characteristics .....	11
Table 14.	Protection and diagnostics .....	11
Table 15.	Truth table.....	12
Table 16.	SOT-223 thermal parameters.....	18
Table 17.	SO-8 thermal parameters.....	21
Table 18.	SOT-223 mechanical data .....	23
Table 19.	SO-8 mechanical data .....	24
Table 20.	Document revision history .....	27

## List of figures

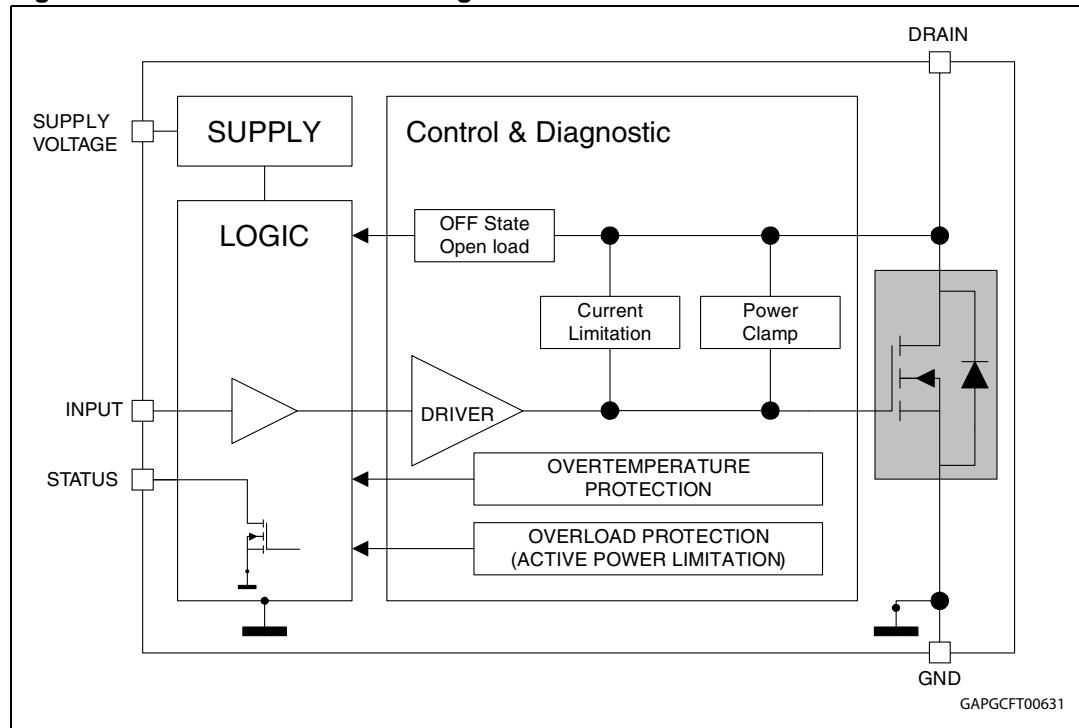
Figure 1.	VNL5090N3-E block diagram .....	5
Figure 2.	VNL5090S5-E block diagram .....	5
Figure 3.	VNL5090N3-E current and voltage conventions .....	6
Figure 4.	VNL5090S5-E current and voltage conventions .....	6
Figure 5.	Configuration diagrams (top view) .....	7
Figure 6.	Switching characteristics .....	12
Figure 7.	VNL5090N3-E application schematic .....	13
Figure 8.	VNL5090S5-E application schematic .....	13
Figure 9.	Maximum demagnetization energy <sup>(1)</sup> .....	15
Figure 10.	SOT-223 PC board .....	16
Figure 11.	SOT-223 Rthj-amb vs PCB copper area in open box free air condition .....	16
Figure 12.	SOT-223 thermal impedance junction ambient single pulse .....	17
Figure 13.	Thermal fitting model of a LSD in SOT-223 .....	17
Figure 14.	SO-8 PC board .....	19
Figure 15.	SO-8 Rthj-amb vs PCB copper area in open box free air condition .....	19
Figure 16.	SO-8 thermal impedance junction ambient single pulse .....	20
Figure 17.	Thermal fitting model of a LSD in SO-8 .....	20
Figure 18.	SOT-223 package dimensions .....	22
Figure 19.	SO-8 package dimensions .....	23
Figure 20.	SOT-223 tape and reel shipment (suffix "TR") .....	25
Figure 21.	SO-8 tube shipment (no suffix) .....	26
Figure 22.	SO-8 tape and reel shipment (suffix "TR") .....	26

# 1 Block diagrams and pins configurations

**Figure 1.** VNL5090N3-E block diagram



**Figure 2.** VNL5090S5-E block diagram

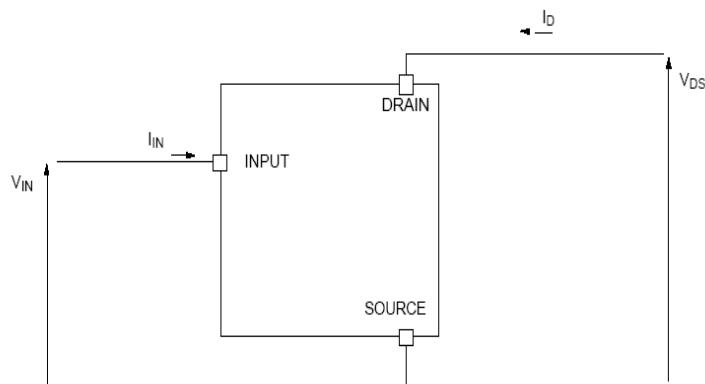
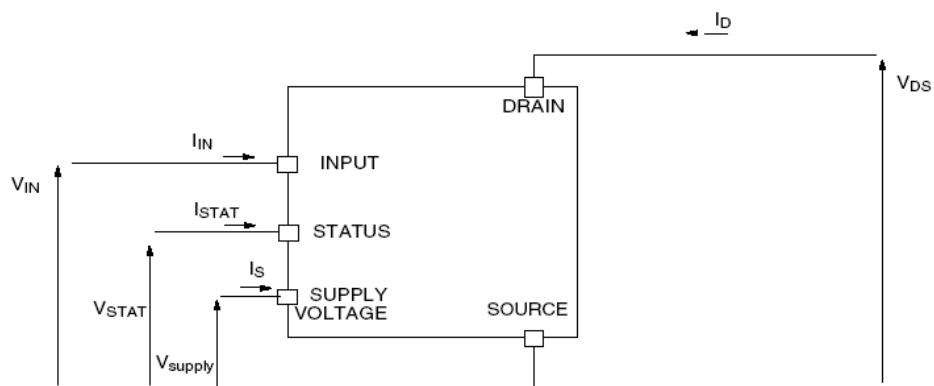


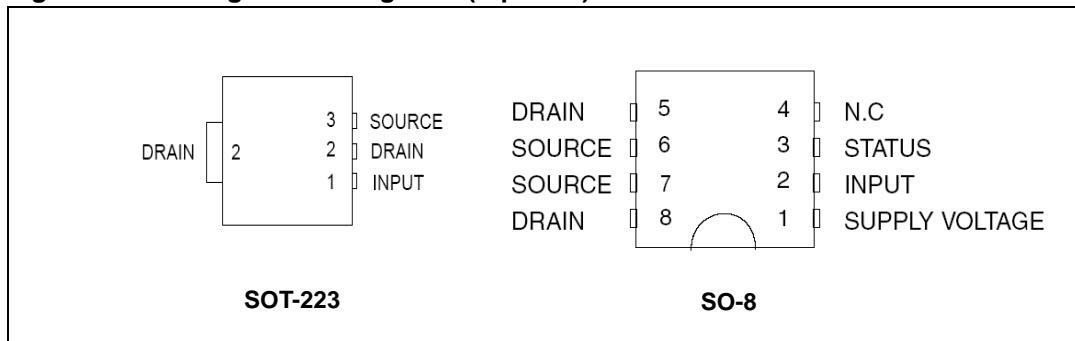
**Table 2. Pin function**

Name	Function
INPUT	Voltage controlled input pin with hysteresis, CMOS compatible; It controls output switch state <sup>(1)</sup>
DRAIN	PowerMOS drain
SOURCE	PowerMOS source and ground reference for the control section
SUPPLY VOLTAGE	Supply voltage connected to the signal part (5 V)
STATUS	Open drain digital diagnostic pin <sup>(2)</sup>

1. Internally connected to  $V_{\text{supply}}$  in the VNL5090N3-E

2. Valid for VNL5090S5-E only.

**Figure 3. VNL5090N3-E current and voltage conventions****Figure 4. VNL5090S5-E current and voltage conventions**

**Figure 5. Configuration diagrams (top view)****Table 3. Suggested connections for unused and N.C. pins**

Connection / pin	Status	N.C.	Input
Floating	X <sup>(1)</sup>	X	X
To ground	Not allowed	X	Through 10 kΩ resistor

1. X: do not care.

## 2 Electrical specifications

### 2.1 Absolute maximum ratings

Stressing the device above the rating listed in the [Table 4](#) may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**Table 4. Absolute maximum ratings**

Symbol	Parameter	Value		Unit
		SOT-223	SO-8	
$V_{DS}$	Drain-source voltage ( $V_{IN} = 0 \text{ V}$ )	Internally clamped		V
$I_D$	DC drain current	Internally limited		A
$-I_D$	Reverse DC drain current	12.5		A
$I_S$	DC supply current	—	-1 to 10	mA
$I_{IN}$	DC input current	-1 to 10		mA
$I_{STAT}$	DC status current	—	-1 to 10	mA
$V_{ESD1}$	Electrostatic discharge ( $R = 1.5 \text{ k}\Omega$ ; $C = 100 \text{ pF}$ ) – DRAIN – SUPPLY, INPUT, STATUS	5000 4000		V V
$V_{ESD2}$	Electrostatic discharge on output pin only ( $R = 330 \Omega$ , $C = 150 \text{ pF}$ )	2000		V
$T_j$	Junction operating temperature	-40 to 150		°C
$T_{stg}$	Storage temperature	-55 to 150		°C
$E_{AS}$	Single pulse avalanche energy ( $L = 1.1 \text{ mH}$ , $T_j = 150^\circ\text{C}$ , $R_L = 0$ , $I_{OUT} = I_{limL}$ )	50		mJ

### 2.2 Thermal data

**Table 5. Thermal data**

Symbol	Parameter	Maximum value		Unit
		SOT-223	SO-8	
$R_{thj-amb}$	Thermal resistance junction-ambient	147 <sup>(1)</sup>	102	°C/W

- When mounted on a standard single-sided FR4 board with  $0.5 \text{ cm}^2$  of Cu (at least  $35 \mu\text{m}$  thick) connected to all DRAIN pins

## 2.3 Electrical characteristics

Values specified in this section are for  $V_{\text{supply}} = V_{\text{IN}} = 4.5 \text{ V}$  to  $5.5 \text{ V}$ ,  $-40^{\circ}\text{C} < T_j < 150^{\circ}\text{C}$ , unless otherwise stated.

**Table 6. PowerMOS section**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{\text{supply}}$	Operating supply voltage		3.5	5	5.5	V
$R_{\text{ON}}$	ON-state resistance	$I_D = 1.6 \text{ A}; T_j = 25^{\circ}\text{C}; V_{\text{supply}} = V_{\text{IN}} = 5 \text{ V}$			90	$\text{m}\Omega$
		$I_D = 1.6 \text{ A}; T_j = 150^{\circ}\text{C}; V_{\text{supply}} = V_{\text{IN}} = 5 \text{ V}$			180	
		$I_D = 1.6 \text{ A}; T_j = 150^{\circ}\text{C}; V_{\text{supply}} = V_{\text{IN}} = 4.5 \text{ V}^{(1)}$			190	
$V_{\text{CLAMP}}$	Drain-source clamp voltage	$V_{\text{IN}} = 0 \text{ V}; I_D = 1.6 \text{ A}$	41	46	52	V
$V_{\text{CLTH}}$	Drain-source clamp threshold voltage	$V_{\text{IN}} = 0 \text{ V}; I_D = 2 \text{ mA}$	36			V
$I_{\text{DSS}}$	OFF-state output current	$V_{\text{IN}} = 0 \text{ V}; V_{\text{DS}} = 13 \text{ V}; T_j = 25^{\circ}\text{C}$	0		3	$\mu\text{A}$
		$V_{\text{IN}} = 0 \text{ V}; V_{\text{DS}} = 13 \text{ V}; T_j = 125^{\circ}\text{C}$	0		5	

1. Valid only for VNL5090N3-E.

**Table 7. Source drain diode**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{\text{SD}}$	Forward on voltage	$I_D = 1.6 \text{ A}; V_{\text{IN}} = 0 \text{ V}$	—	0.8	—	V

**Table 8. Input section<sup>(1)</sup>**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$I_{\text{ISS}}$	Supply current from input pin	ON-state: $V_{\text{supply}} = V_{\text{IN}} = 5 \text{ V}; V_{\text{DS}} = 0 \text{ V}$		30	110	$\mu\text{A}$
$V_{\text{ICL}}$	Input clamp voltage	$I_S = 1 \text{ mA}$	5.5		7	V
		$I_S = -1 \text{ mA}$		-0.7		
$V_{\text{INTH}}$	Input threshold voltage	$V_{\text{DS}} = V_{\text{IN}}; I_D = 1 \text{ mA}$	1		3.5	V

1. Valid for VNL5090N3-E option (input and supply pins connected together)

**Table 9. Status pin<sup>(1)</sup>**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{\text{STAT}}$	Status low output voltage	$I_{\text{STAT}} = 1 \text{ mA}$			0.5	V
$I_{\text{LSTAT}}$	Status leakage current	Normal operation, $V_{\text{STAT}} = 5 \text{ V}$			10	$\mu\text{A}$

**Table 9. Status pin<sup>(1)</sup> (continued)**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$C_{STAT}$	Status pin input capacitance	Normal operation, $V_{STAT} = 5\text{ V}$			100	pF
$V_{STCL}$	Status clamp voltage	$I_{STAT} = 1\text{ mA}$	5.5		7	V
		$I_{STAT} = -1\text{ mA}$		-0.7		

1. Valid for VNL5090S5-E option

**Table 10. Logic input<sup>(1)</sup>**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{IL}$	Low-level input voltage				0.9	V
$I_{IL}$	Low-level input current	$V_{IN} = 0.9\text{ V}$	1			$\mu\text{A}$
$V_{IH}$	High-level input voltage		2.1			V
$I_{IH}$	High-level input current	$V_{IN} = 2.1\text{ V}$			10	$\mu\text{A}$
$V_{I(hyst)}$	Input hysteresis voltage		0.13			V
$V_{ICL}$	Input clamp voltage	$I_{IN} = 1\text{ mA}$	5.5		7	V
		$I_{IN} = -1\text{ mA}$		-0.7		

1. Valid for VNL5090S5-E option

**Table 11. Openload detection<sup>(1)</sup>**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{OI}$	Openload OFF-state voltage detection threshold	$V_{IN} = 0\text{ V}$	0.6	1.2	1.7	V
$t_{d(oloff)}$	Delay between INPUT falling edge and STATUS falling edge in openload condition	$I_{OUT} = 0\text{ A}$	45	425	1100	$\mu\text{s}$

1. Valid for VNL5090S5-E option

**Table 12. Supply section<sup>(1)</sup>**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$I_S$	Supply current	OFF-state; $T_j = 25^\circ\text{C}$ ; $V_{IN} = V_{DRAIN} = 0\text{ V}$ ;		10	25	$\mu\text{A}$
		ON-state; $V_{IN} = 5\text{ V}$ ; $V_{DS} = 0\text{ V}$		25	110	
$V_{SCL}$	Supply clamp voltage	$I_{SCL} = 1\text{ mA}$	5.5		7	V
		$I_{SCL} = -1\text{ mA}$		-0.7		

1. Valid for VNL5090S5-E option

**Table 13. Switching characteristics<sup>(1)</sup>**

Symbol	Parameter	Test conditions	SOT-223 <sup>(2)</sup>			SO-8			Unit
			Min.	Typ.	Max	Min.	Typ.	Max.	
$t_{d(ON)}$	Turn-on delay time	$R_L = 8.2 \Omega$ , $V_{CC} = 13 \text{ V}^{(3)}$	—	8	—	—	8	—	μs
$t_{d(OFF)}$	Turn-off delay time	$R_L = 8.2 \Omega$ , $V_{CC} = 13 \text{ V}^{(3)}$	—	3.4	—	—	18	—	μs
$t_r$	Rise time	$R_L = 8.2 \Omega$ , $V_{CC} = 13 \text{ V}^{(3)}$	—	10	—	—	10	—	μs
$t_f$	Fall time	$R_L = 8.2 \Omega$ , $V_{CC} = 13 \text{ V}^{(3)}$	—	2.7	—	—	10	—	μs
$W_{ON}$	Switching energy losses at turn-on	$R_L = 8.2 \Omega$ , $V_{CC} = 13 \text{ V}^{(3)}$	—	57	—	—	57	—	mJ
$W_{OFF}$	Switching energy losses at turn-off	$R_L = 8.2 \Omega$ , $V_{CC} = 13 \text{ V}^{(3)}$	—	14	—	—	55	—	mJ

1. See [Figure 7: VNL5090N3-E application schematic](#) and [Figure 8: VNL5090S5-E application schematic](#)2.  $3.5 \text{ V} \leq V_{\text{supply}} = V_{IN} \leq 5.5 \text{ V}$ 3. See [Figure 6: Switching characteristics](#)**Table 14. Protection and diagnostics**

Symbol	Parameter	Test conditions <sup>(1)</sup>	Min.	Typ.	Max.	Unit
$I_{limH}$	DC short-circuit current	$V_{DS} = 13 \text{ V}$ ; $V_{\text{supply}} = V_{IN} = 5 \text{ V}$	13	18	25	A
$I_{limL}$	Short-circuit current during thermal cycling	$V_{DS} = 13 \text{ V}$ ; $T_R < T_j < T_{TSD}$ ; $V_{\text{supply}} = V_{IN} = 5 \text{ V}$		8		A
$t_{dlmL}$	Step response current limit	$V_{DS} = 13 \text{ V}$ ; $V_{\text{input}} = 5 \text{ V}$		44		μs
$T_{TSD}$	Shutdown temperature		150	175	200	°C
$T_R^{(2)}$	Reset temperature		$T_{RS} + 1$	$T_{RS} + 5$		°C
$T_{RS}^{(3)}$	Thermal reset of STATUS		135			°C
$T_{HYST}$	Thermal hysteresis ( $T_{TSD} - T_R$ )			7		°C

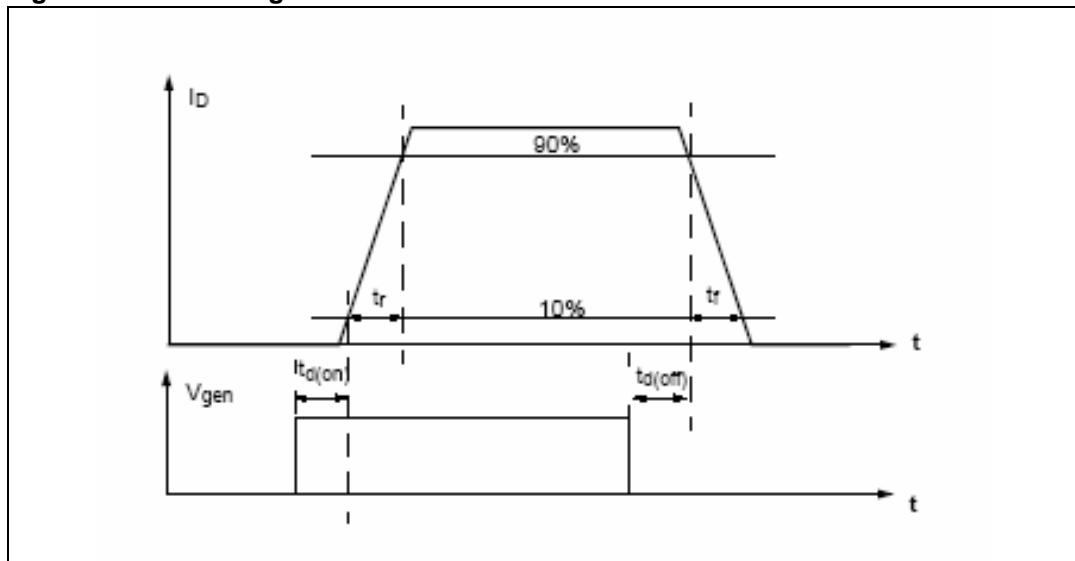
1.  $V_{\text{supply}} = V_{\text{input}}$  in VNL5090N3-E version.

2. Valid for VNL5090S5-E option.

**Table 15. Truth table<sup>(1)</sup>**

Conditions	INPUT	DRAIN	STATUS
Normal operation	L	H	H
	H	L	H
Current limitation	L	H	H
	H	X	H
Overtemperature	L	H	H
	H	H	L
Undervoltage	L	H	X
	H	H	X
Output voltage < $V_{OL}$	L	L	L
	H	L	H

1. Valid for VNL5090S5-E option

**Figure 6. Switching characteristics**

### 3 Application information

Figure 7. VNL5090N3-E application schematic

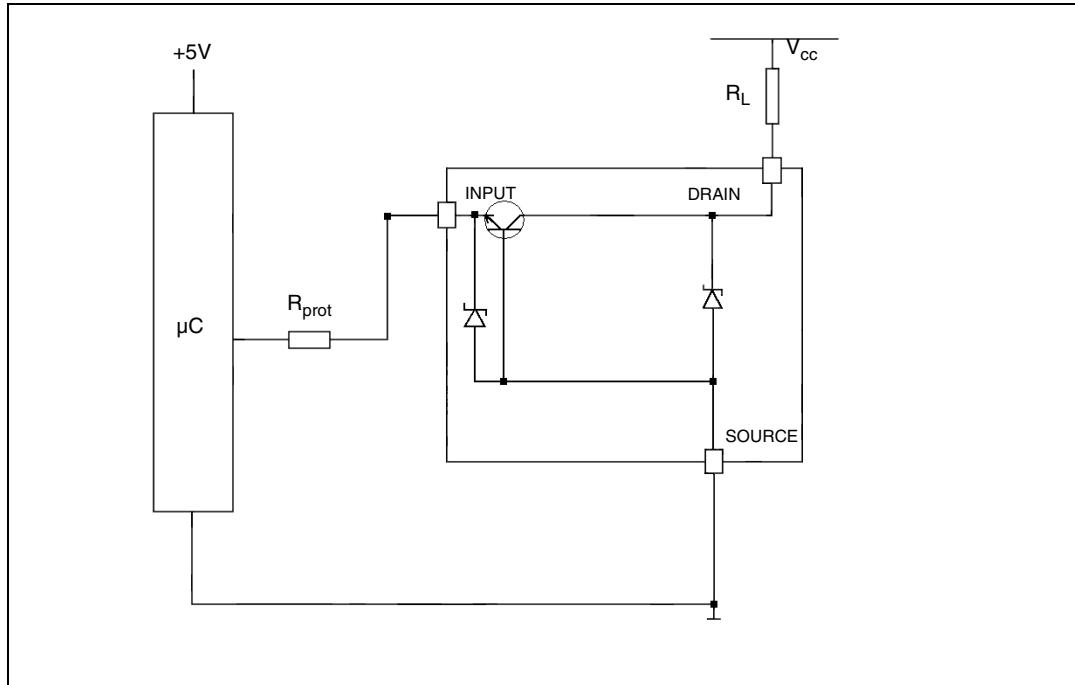
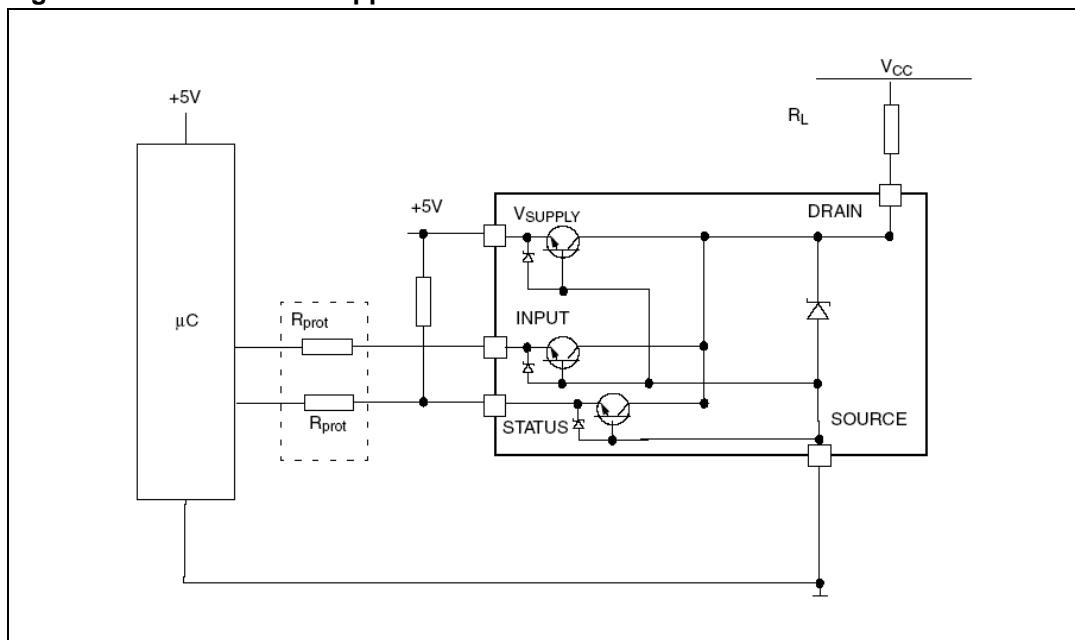


Figure 8. VNL5090S5-E application schematic



### 3.1 MCU I/O protection

ST suggests to insert a resistor ( $R_{prot}$ ) in line to prevent the microcontroller I/O pins from latching up<sup>(a)</sup>. The value of these resistors is a compromise between the leakage current of microcontroller and the current required by the LSD I/Os (input levels compatibility) with the latch-up limit of microcontroller I/Os:

**Equation 1**

$$\frac{0.7}{I_{latchup}} \leq R_{prot} \leq \frac{(V_{O\mu C} - V_{IH})}{I_{IH\ max}}$$

Let:

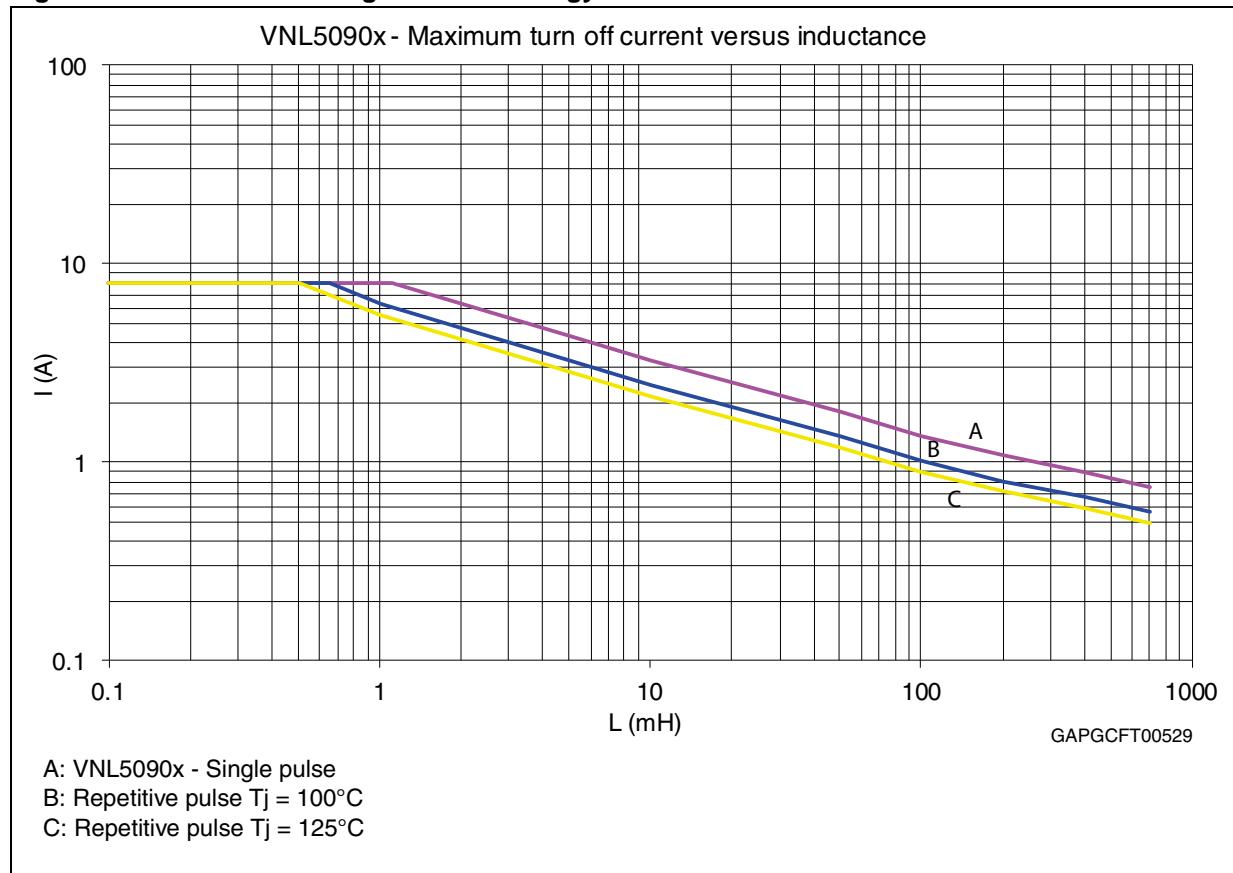
- $I_{latchup} \geq 20 \text{ mA}$
- $V_{O\mu C} \geq 4.5 \text{ V}$
- $35 \Omega \leq R_{prot} \leq 100 \text{ K}\Omega$

Then, the recommended value is  $R_{prot} = 10 \text{ K}\Omega$

*Figure 9* shows the turn-off current drawn during the demagnetization.

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a. In case of negative transient on the drain pin.

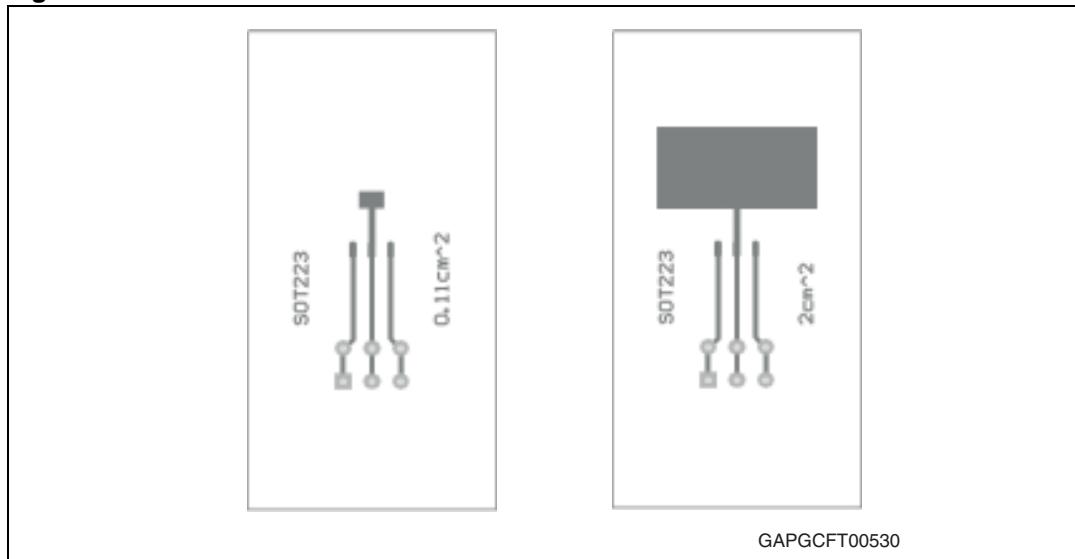
**Figure 9. Maximum demagnetization energy<sup>(1)</sup>**

1. The voltage supply is  $V_{CC} = 13.5 \text{ V}$ .

## 4 Package and PC board thermal data

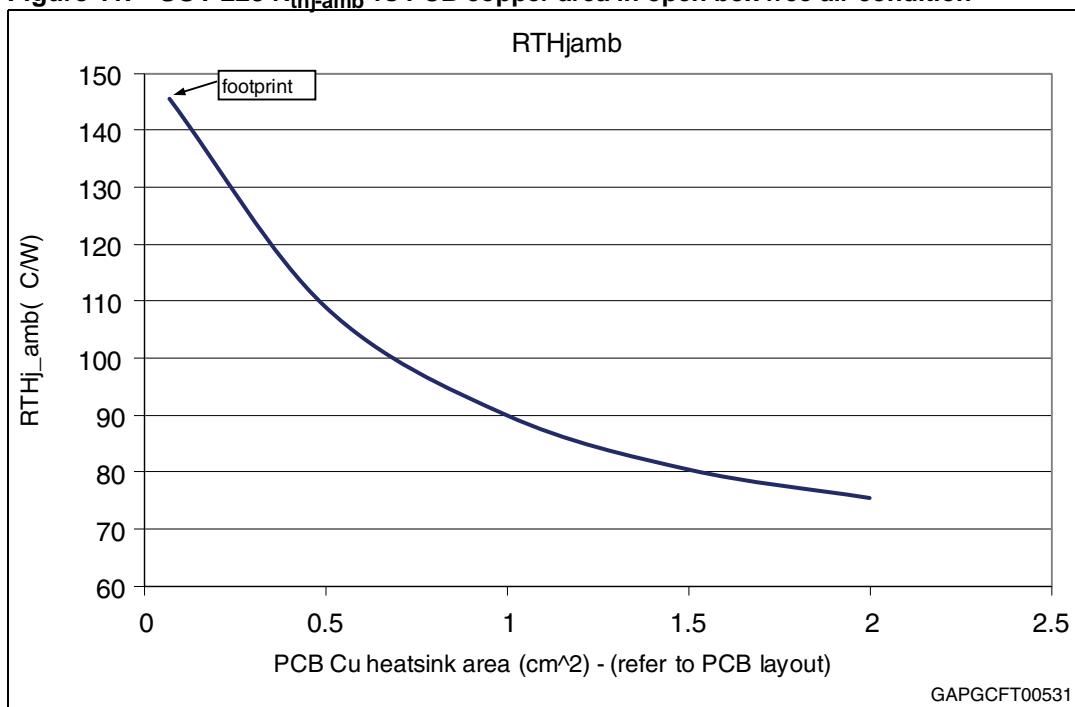
### 4.1 SOT-223 thermal data

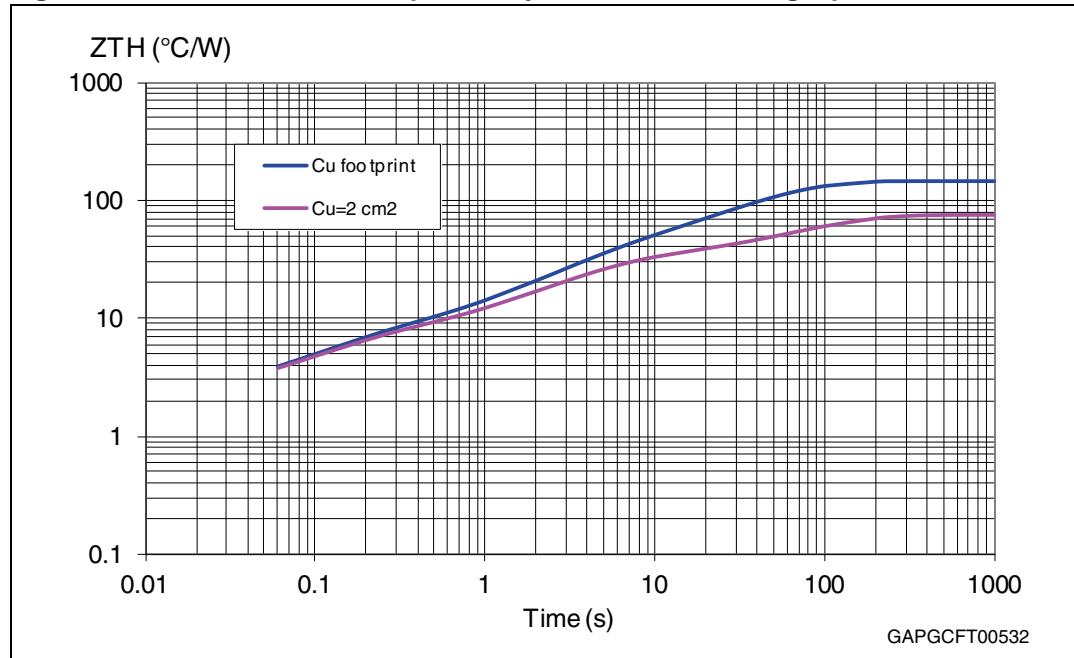
**Figure 10.** SOT-223 PC board



**Note:** Layout condition of  $R_{th}$  and  $Z_{th}$  measurements (PCB FR4 area = 30 mm x 58 mm, PCB thickness = 2 mm, Cu thickness = 35  $\mu$ m, copper areas: from minimum pad lay-out to 0.8  $cm^2$ ).

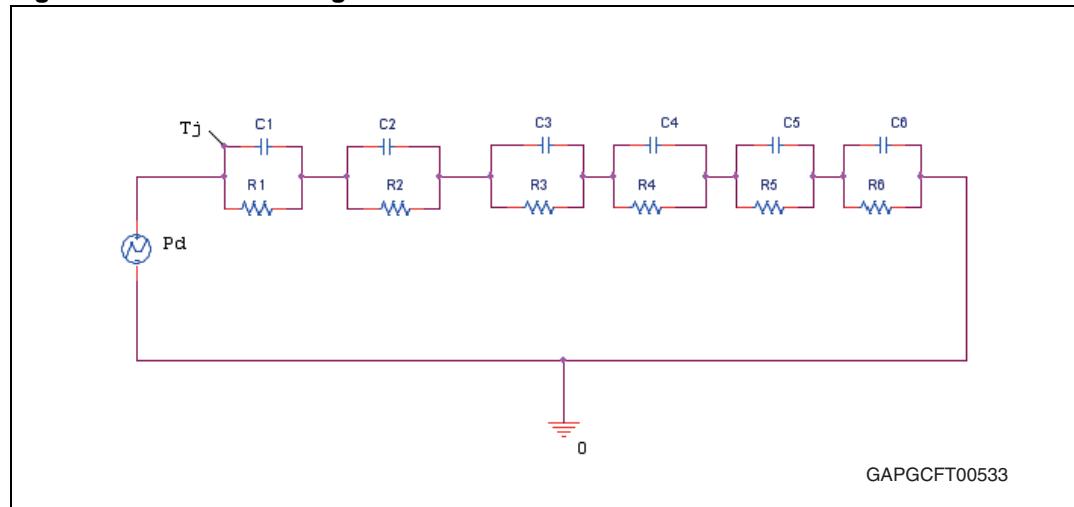
**Figure 11.** SOT-223  $R_{th,j,amb}$  vs PCB copper area in open box free air condition



**Figure 12.** SOT-223 thermal impedance junction ambient single pulse**Equation 2:** pulse calculation formula

$$Z_{TH\delta} = R_{TH} \cdot \delta + Z_{THtp}(1 - \delta)$$

where  $\delta = t_p/T$

**Figure 13.** Thermal fitting model of a LSD in SOT-223

Note:

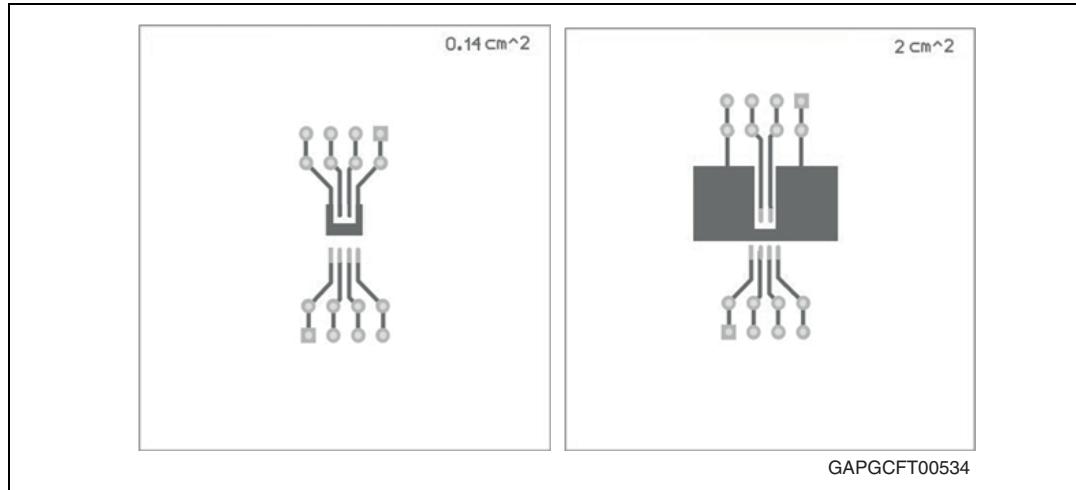
The fitting model is a simplified thermal tool and is valid for transient evolutions where the embedded protections (power limitation or thermal cycling during thermal shutdown) are not triggered.

**Table 16. SOT-223 thermal parameters**

Area/island (cm <sup>2</sup> )	Footprint	2
R1 (°C/W)	0.8	
R2 (°C/W)	1	
R3 (°C/W)	4.5	
R4 (°C/W)	24	
R5 (°C/W)	0.1	
R6 (°C/W)	115	45
C1 (W.s/°C)	0.00004	
C2 (W.s/°C)	0.0003	
C3 (W.s/°C)	0.03	
C4 (W.s/°C)	0.16	
C5 (W.s/°C)	1000	
C6 (W.s/°C)	0.4	2

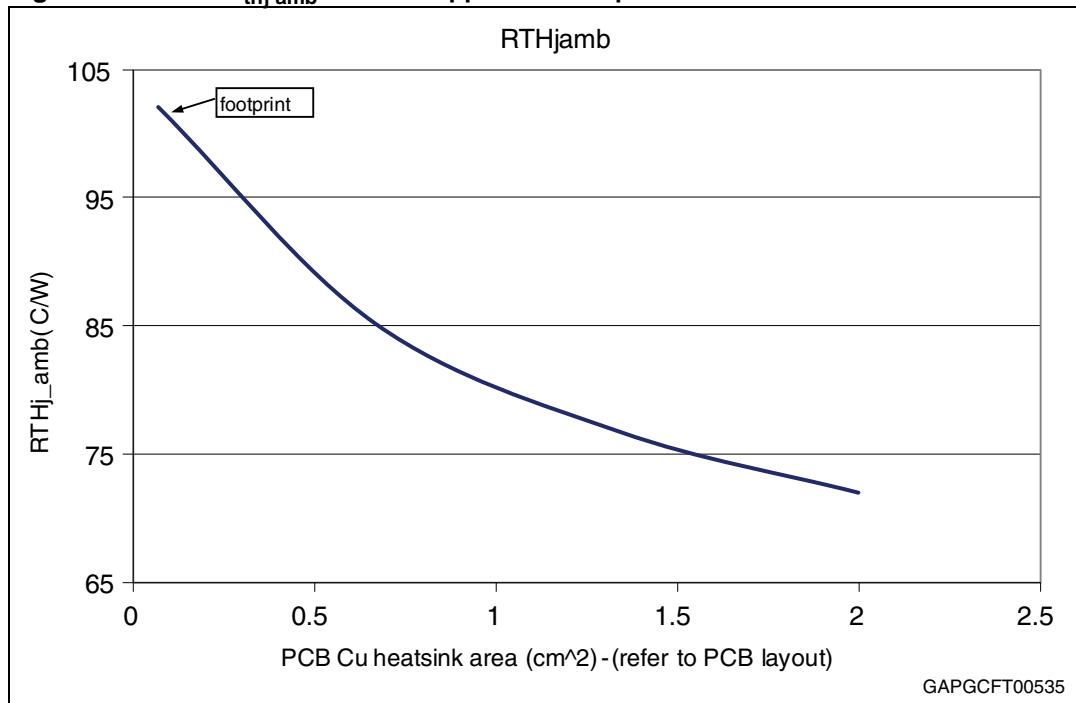
## 4.2 SO-8 thermal data

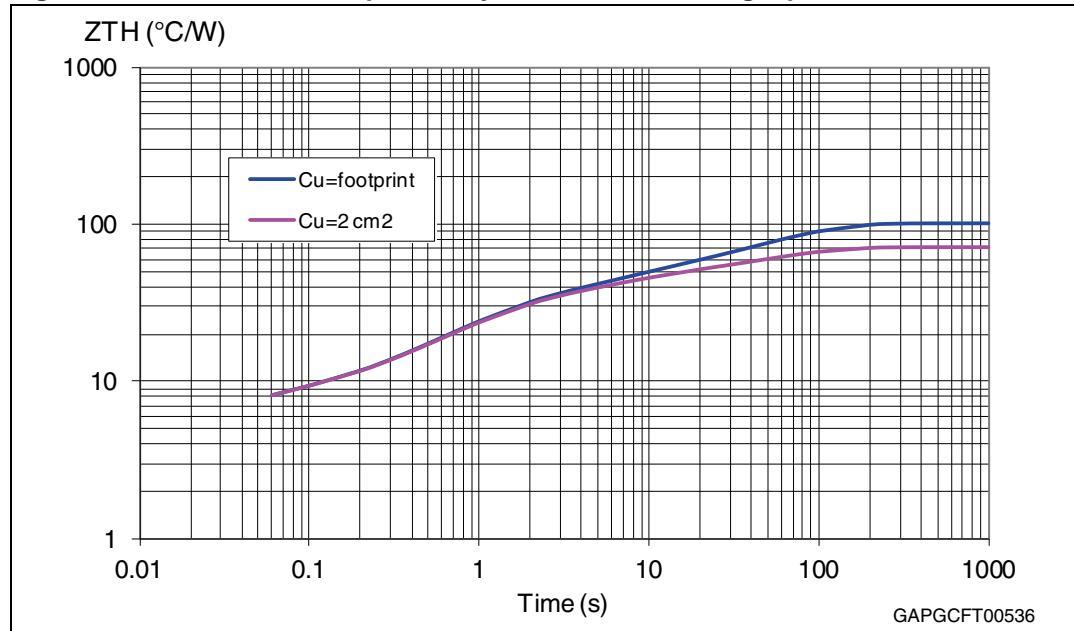
**Figure 14.** SO-8 PC board



**Note:** Layout condition of  $R_{th}$  and  $Z_{th}$  measurements (PCB FR4 area = 58 mm x 58 mm, PCB thickness = 2 mm, Cu thickness = 35  $\mu\text{m}$  (front and back side), Copper areas: from minimum pad lay-out to  $2 \text{ cm}^2$ ).

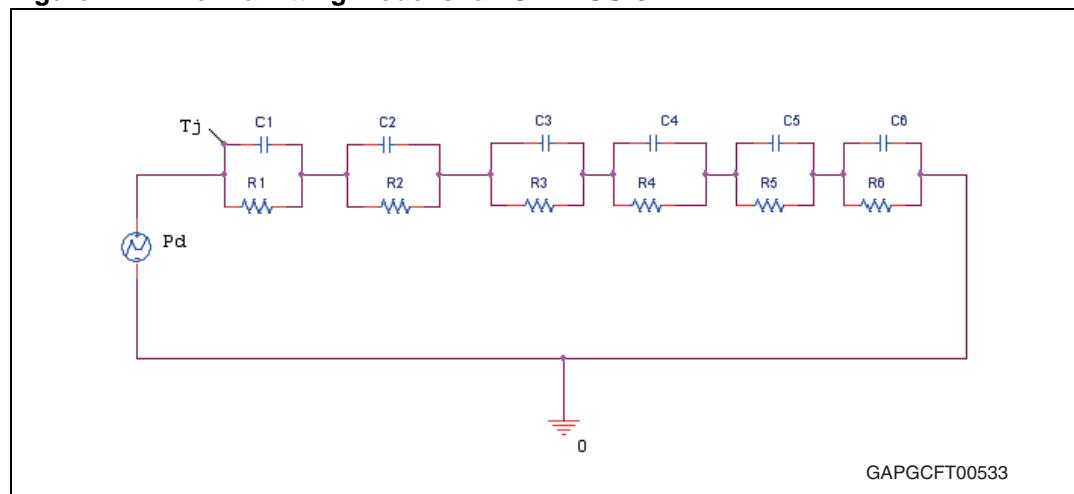
**Figure 15.** SO-8  $R_{thj\text{-amb}}$  vs PCB copper area in open box free air condition



**Figure 16.** SO-8 thermal impedance junction ambient single pulse**Equation 3:** pulse calculation formula

$$Z_{TH\delta} = R_{TH} \cdot \delta + Z_{THtp}(1 - \delta)$$

where  $\delta = t_p/T$

**Figure 17.** Thermal fitting model of a LSD in SO-8

Note:

*The fitting model is a simplified thermal tool and is valid for transient evolutions where the embedded protections (power limitation or thermal cycling during thermal shutdown) are not triggered.*

**Table 17. SO-8 thermal parameters**

Area/island (cm <sup>2</sup> )	Footprint	2
R1 (°C/W)	0.8	
R2 (°C/W)	2.7	
R3 (°C/W)	3.5	
R4 (°C/W)	21	
R5 (°C/W)	16	
R6 (°C/W)	58	28
C1 (W.s/°C)	0.00005	
C2 (W.s/°C)	0.001	
C3 (W.s/°C)	0.0075	
C4 (W.s/°C)	0.045	
C5 (W.s/°C)	0.35	
C6 (W.s/°C)	1.05	2

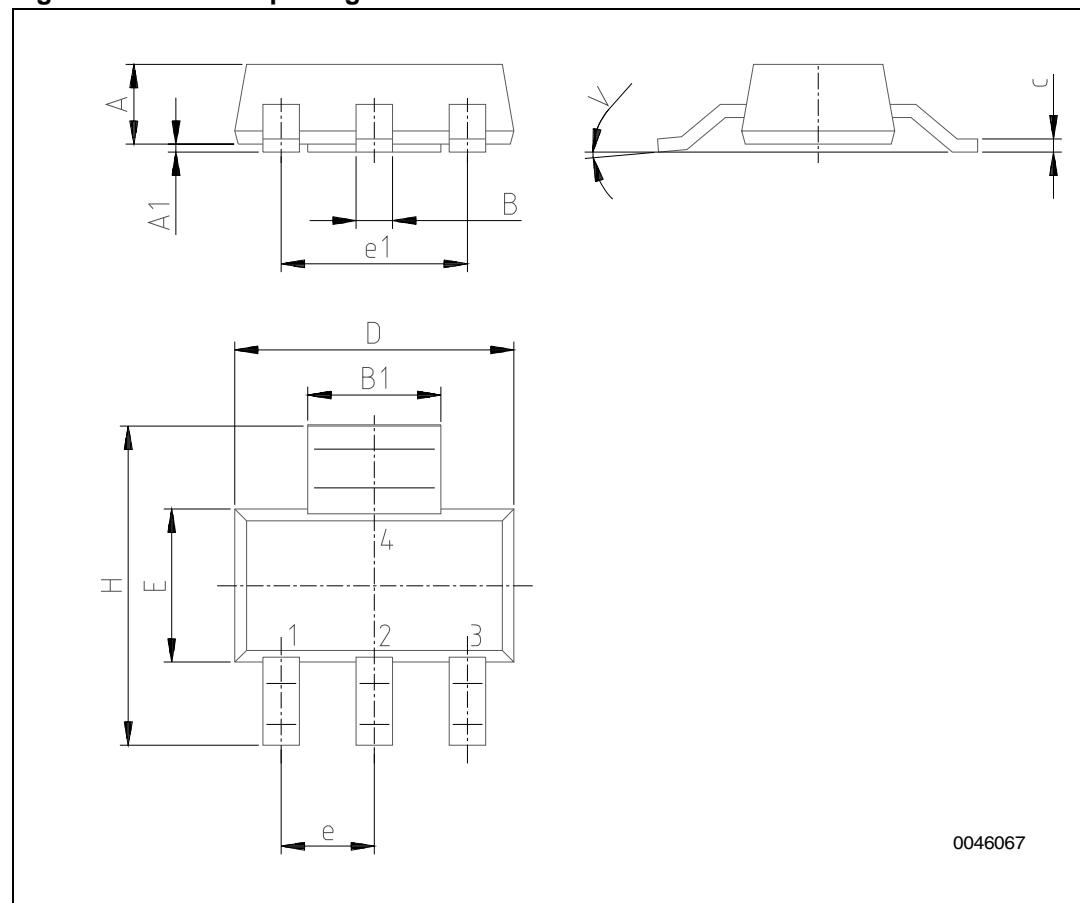
## 5 Package and packing information

### 5.1 ECOPACK®

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com).  
ECOPACK® is an ST trademark.

### 5.2 SOT-223 mechanical data

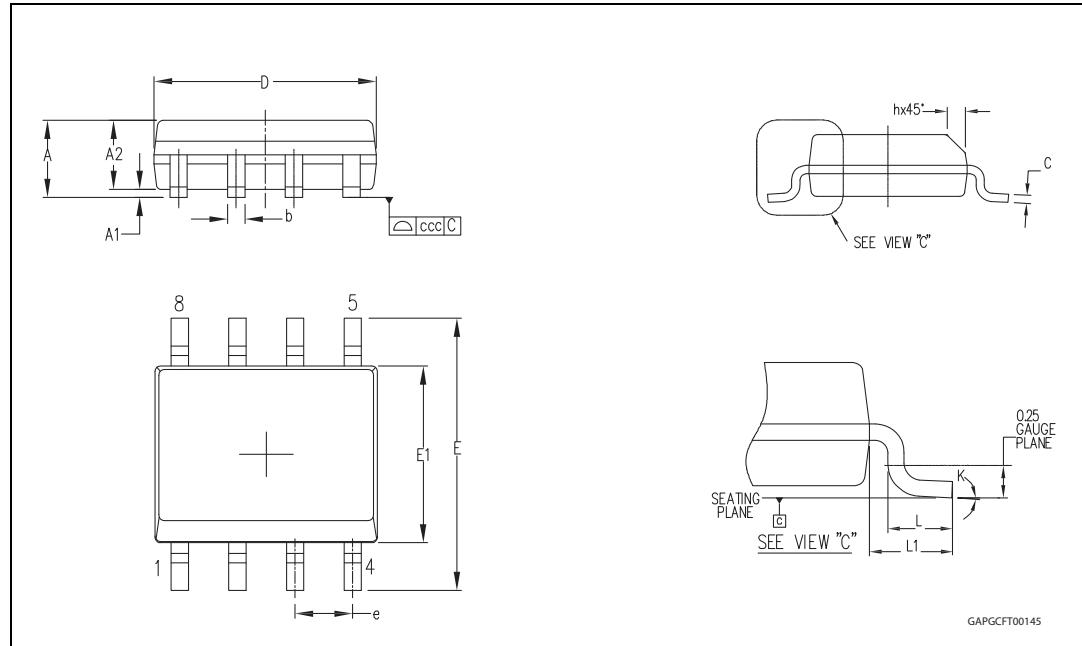
Figure 18. SOT-223 package dimensions



**Table 18. SOT-223 mechanical data**

DIM.	mm.			inch		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.8			0.071
B	0.6	0.7	0.85	0.024	0.027	0.033
B1	2.9	3	3.15	0.114	0.118	0.124
c	0.24	0.26	0.35	0.009	0.01	0.014
D	6.3	6.5	6.7	0.248	0.256	0.264
e		2.3			0.09	
e1		4.6			0.181	
E	3.3	3.5	3.7	0.13	0.138	0.146
H	6.7	7	7.3	0.264	0.276	0.287
V	10 (max)					
A1	0.02		0.1	0.0008		0.004

### 5.3 SO-8 mechanical data

**Figure 19. SO-8 package dimensions**

**Table 19. SO-8 mechanical data**

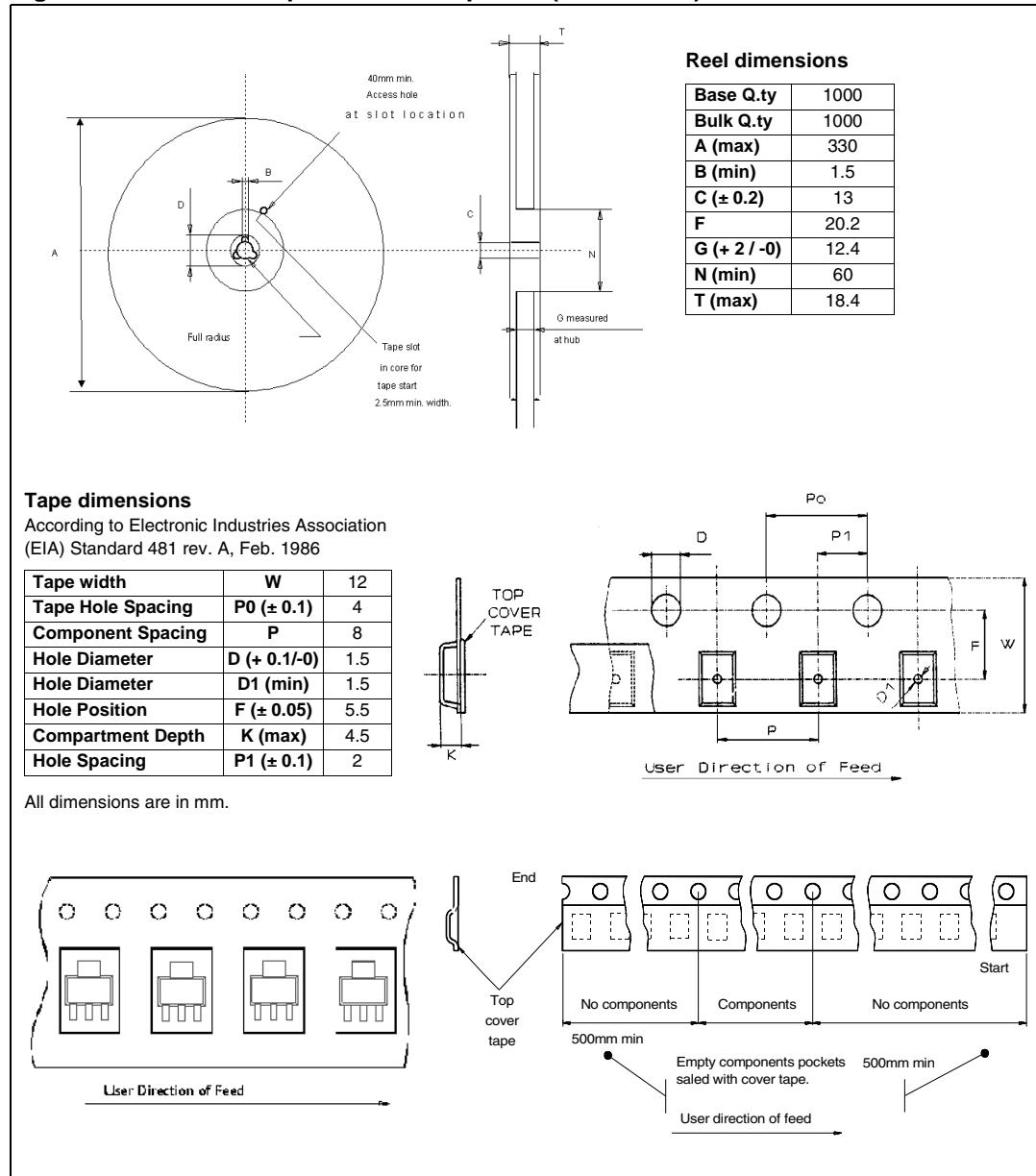
Symbol	Millimeters		
	Min.	Typ.	Max.
A			1.75
A1	0.10		0.25
A2	1.25		
b	0.28		0.48
c	0.17		0.23
D <sup>(1)</sup>	4.80	4.90	5.00
E	5.80	6.00	6.20
E1 <sup>(2)</sup>	3.80	3.90	4.00
e		1.27	
h	0.25		0.50
L	0.40		1.27
L1		1.04	
k	0°		8°
ccc			0.10

1. Dimensions D does not include mold flash, protrusions or gate burrs. Mold flash, potrusions or gate burrs shall not exceed 0.15 mm in total (both side).
2. Dimension "E1" does not include interlead flash or protrusions. Interlead flash or protrusions shall not exceed 0.25 mm per side.

## 5.4 SOT-223 packing information

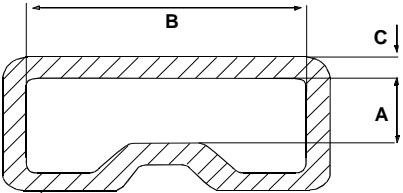
The devices can be packed in tube or tape and reel shipments (see the [Table 1: Devices summary on page 1](#)).

**Figure 20. SOT-223 tape and reel shipment (suffix “TR”)**



## 5.5 SO-8 packing information

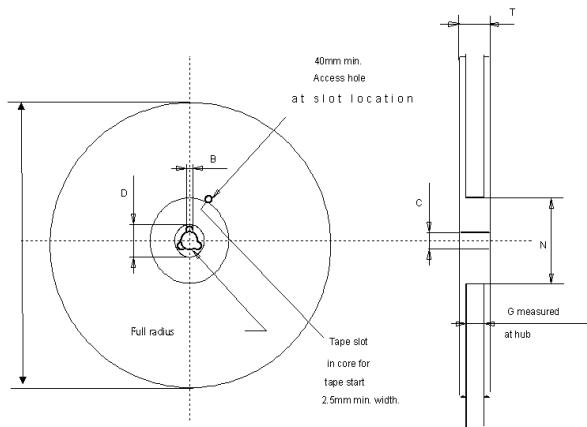
**Figure 21. SO-8 tube shipment (no suffix)**



<b>Base q.ty</b>	100
<b>Bulk q.ty</b>	2000
<b>Tube length (<math>\pm 0.5</math>)</b>	532
<b>A</b>	3.2
<b>B</b>	6
<b>C (<math>\pm 0.1</math>)</b>	0.6

All dimensions are in mm.

**Figure 22. SO-8 tape and reel shipment (suffix “TR”)**



<b>Reel dimensions</b>	
<b>Base q.ty</b>	2500
<b>Bulk q.ty</b>	2500
<b>A (max)</b>	330
<b>B (min)</b>	1.5
<b>C (<math>\pm 0.2</math>)</b>	13
<b>F</b>	20.2
<b>G (<math>+ 2 / -0</math>)</b>	12.4
<b>N (min)</b>	60
<b>T (max)</b>	18.4

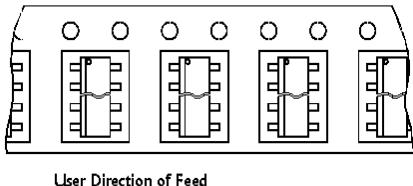
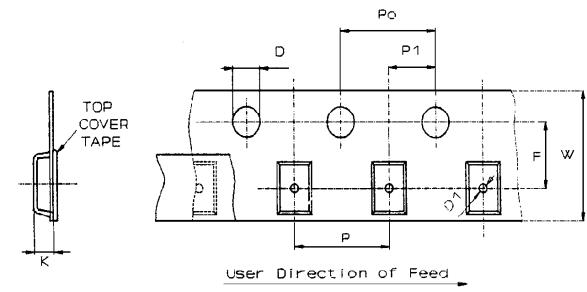
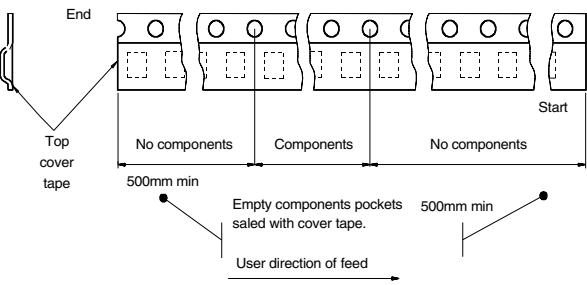
All dimensions are in mm.

**Tape dimensions**  
According to Electronic Industries Association (EIA) Standard 481 rev. A, Feb. 1986

<b>Tape width</b>	<b>W</b>	12
<b>Tape hole spacing</b>	<b>P0 (<math>\pm 0.1</math>)</b>	4
<b>Component spacing</b>	<b>P</b>	8
<b>Hole diameter</b>	<b>D (<math>+ 0.1/-0</math>)</b>	1.5
<b>Hole diameter</b>	<b>D1 (min)</b>	1.5
<b>Hole position</b>	<b>F (<math>\pm 0.05</math>)</b>	5.5
<b>Compartment depth</b>	<b>K (max)</b>	4.5
<b>Hole spacing</b>	<b>P1 (<math>\pm 0.1</math>)</b>	2

All dimensions are in mm.

## 6 Revision history

**Table 20. Document revision history**

Date	Revision	Changes
15-Dec-2011	1	Initial release.
20-Jan-2012	2	<i>Table 4: Absolute maximum ratings:</i> – $-I_D$ : updated value
18-Apr-2012	3	Updated <i>Features</i> list

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